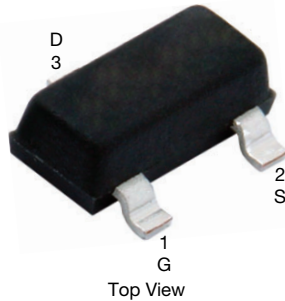


P-Channel 20 V (D-S) MOSFET

SOT-23 (TO-236)



Top View

Marking code: H7

PRODUCT SUMMARY	
V_{DS} (V)	-20
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -4.5$ V	0.066
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -2.5$ V	0.086
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -1.8$ V	0.130
Q_g typ. (nC)	9
I_D (A) ^d	-3.8
Configuration	Single

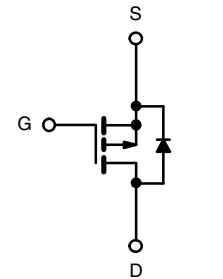
FEATURES

- TrenchFET[®] power MOSFET
- 100 % R_g tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
 COMPLIANT
 HALOGEN
FREE

APPLICATIONS

- Load switch for portable devices
- DC/DC converter



P-Channel MOSFET

ORDERING INFORMATION	
Package	SOT-23
Lead (Pb)-free and halogen-free	Si2367DS-T1-GE3

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT
Drain-source voltage	V_{DS}	-20	V
Gate-source voltage	V_{GS}	± 8	
Continuous drain current ($T_J = 150$ °C)	I_D	$T_C = 25$ °C	-3.8
		$T_C = 70$ °C	-3
		$T_A = 25$ °C	-2.8 ^{a, b}
		$T_A = 70$ °C	-2.2 ^{a, b}
Pulsed drain current (10 μ s width)	I_{DM}	-15	A
Continuous source-drain diode current	I_S	$T_C = 25$ °C	
		$T_A = 25$ °C	-0.8 ^{a, b}
Maximum power dissipation	P_D	$T_C = 25$ °C	1.7
		$T_C = 70$ °C	1.1
		$T_A = 25$ °C	0.96 ^{a, b}
		$T_A = 70$ °C	0.62 ^{a, b}
Operating junction and storage temperature range	T_J, T_{stg}	-55 to +150	°C

THERMAL RESISTANCE RATINGS				
PARAMETER	SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient ^{a, c}	R_{thJA}	100	130	°C/W
Maximum junction-to-foot (drain)	R_{thJF}	60	75	
				Steady state

Notes

- Surface mounted on 1" x 1" FR4 board
- $t = 5$ s
- Maximum under steady state conditions is 175 °C/W
- $T_C = 25$ °C



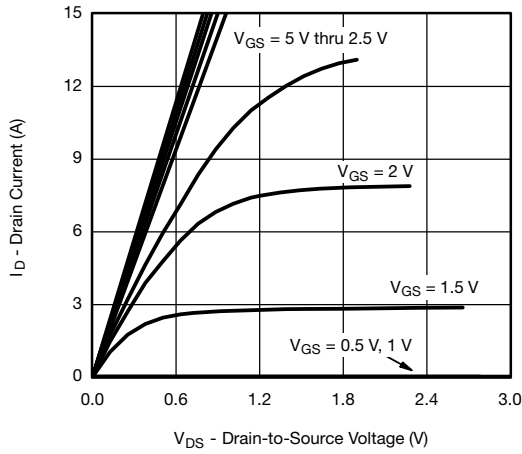
SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0 V, I _D = -250 μA	-20	-	-	V
V _{DS} temperature coefficient	ΔV _{DS} /T _J	I _D = -250 μA	-	-20	-	mV/°C
V _{GS(th)} temperature coefficient	ΔV _{GS(th)} /T _J		-	-2.5	-	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250 μA	-0.4	-	-1	V
Gate-source leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 8 V	-	-	± 100	nA
Zero gate voltage drain current	I _{DSS}	V _{DS} = -20 V, V _{GS} = 0 V	-	-	-1	μA
		V _{DS} = -20 V, V _{GS} = 0 V, T _J = 55 °C	-	-	-10	
On-state drain current ^a	I _{D(on)}	V _{DS} ≤ -5 V, V _{GS} = -4.5 V	-5	-	-	A
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = -4.5 V, I _D = -2.5 A	-	0.055	0.066	Ω
		V _{GS} = -2.5 V, I _D = -2 A	-	0.071	0.086	
		V _{GS} = -1.8 V, I _D = -1.5 A	-	0.100	0.130	
Forward transconductance ^a	g _{fs}	V _{DS} = -10 V, I _D = -2.5 A	-	7.5	-	S
Dynamic ^b						
Input capacitance	C _{iss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	-	561	-	pF
Output capacitance	C _{oss}		-	112	-	
Reverse transfer capacitance	C _{rss}		-	89	-	
Total gate charge	Q _g	V _{DS} = -10 V, V _{GS} = -8 V, I _D = -2.5 A	-	15	23	nC
		V _{DS} = -10 V, V _{GS} = -4.5 V, I _D = -2.5 A	-	9	13.5	
Gate-source charge	Q _{gs}		-	1	-	
Gate-drain charge	Q _{gd}		-	2.5	-	
Gate resistance	R _g	f = 1 MHz	2	10	20	Ω
Turn-on delay time	t _{d(on)}	V _{DD} = -10 V, R _L = 5 Ω, I _D ≅ -2 A, V _{GEN} = -4.5 V, R _g = 1 Ω	-	20	40	ns
Rise time	t _r		-	20	40	
Turn-off delay time	t _{d(off)}		-	40	70	
Fall time	t _f		-	10	20	
Turn-on delay time	t _{d(on)}	V _{DD} = -10 V, R _L = 5 Ω, I _D ≅ -2 A, V _{GEN} = -8 V, R _g = 1 Ω	-	8	16	
Rise time	t _r		-	9	18	
Turn-off delay time	t _{d(off)}		-	35	65	
Fall time	t _f		-	9	18	
Drain-Source Body Diode Characteristics						
Continuous source-drain diode current	I _S	T _C = 25 °C	-	-	-1.4	A
Pulse diode forward current	I _{SM}		-	-	-15	
Body diode voltage	V _{SD}	I _S = -2 A, V _{GS} = 0 V	-	-0.79	-1.2	V
Body diode reverse recovery time	t _{rr}	I _F = -2 A, di/dt = 100 A/μs, T _J = 25 °C	-	21	35	ns
Body diode reverse recovery charge	Q _{rr}		-	15	25	nC
Reverse recovery fall time	t _a		-	9	-	ns
Reverse recovery rise time	t _b		-	12	-	

Notes

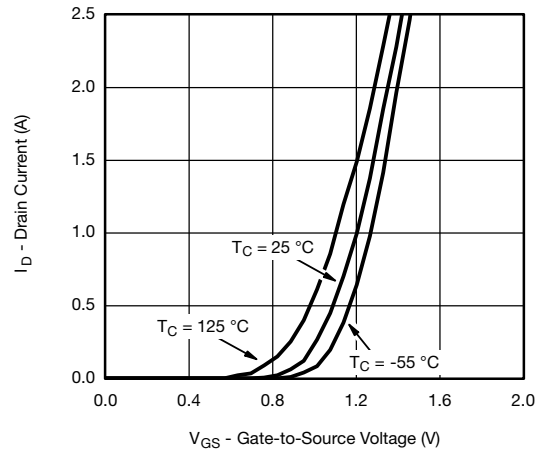
- a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %
- b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

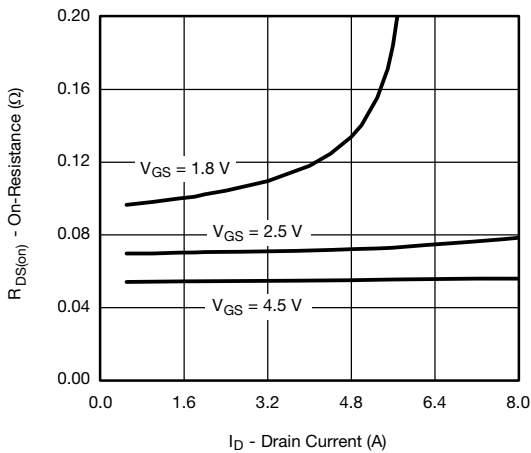
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



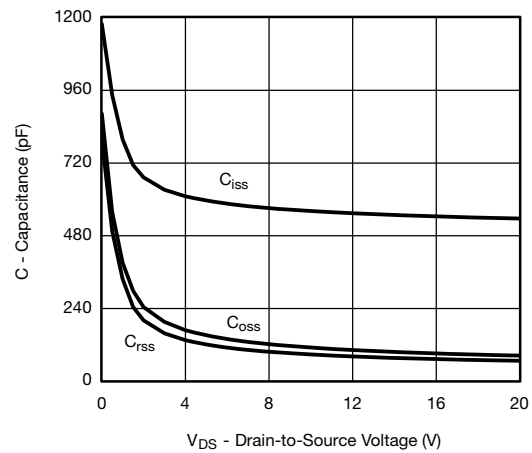
Output Characteristics



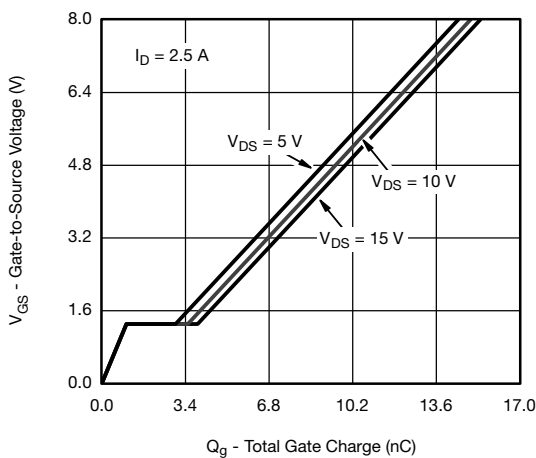
Transfer Characteristics



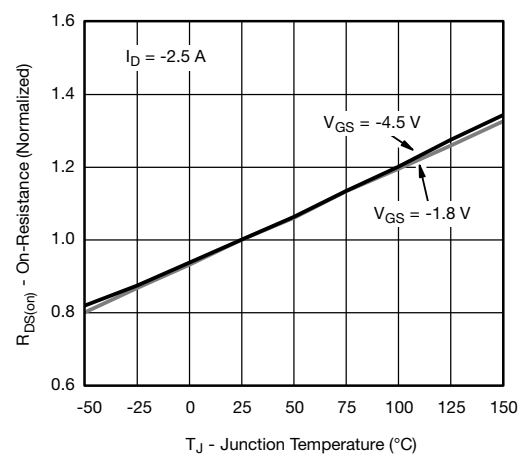
On-Resistance vs. Drain Current and Gate Voltage



Capacitance



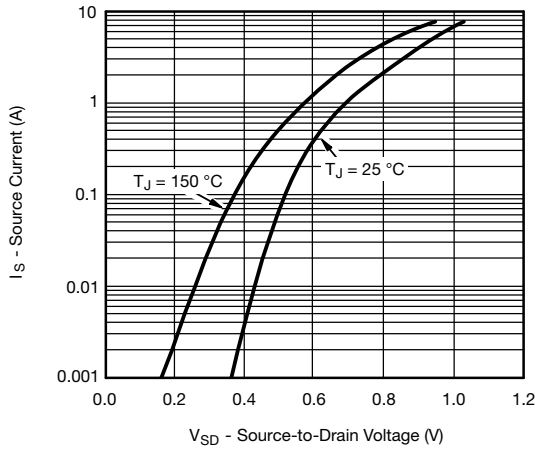
Gate Charge



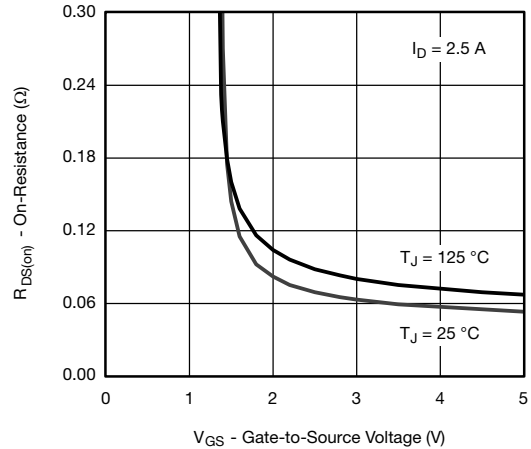
On-Resistance vs. Junction Temperature



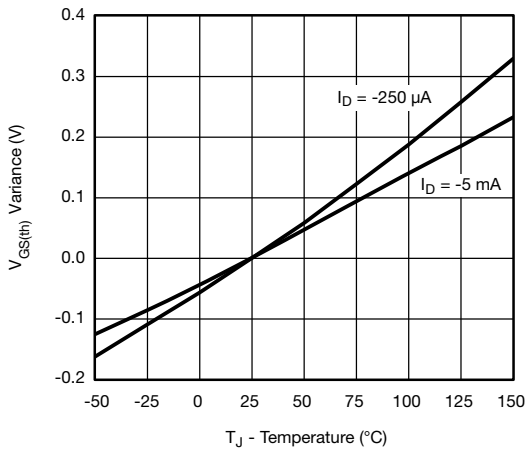
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



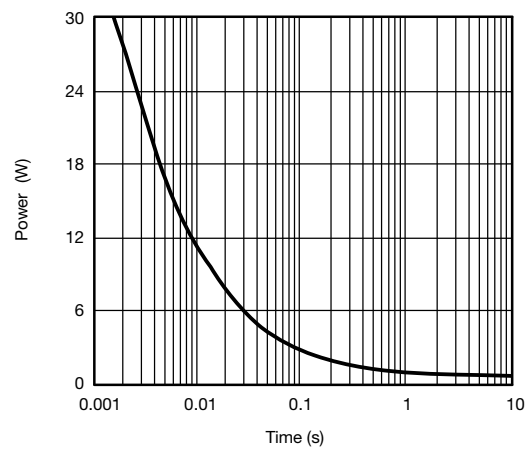
Source-Drain Diode Forward Voltage



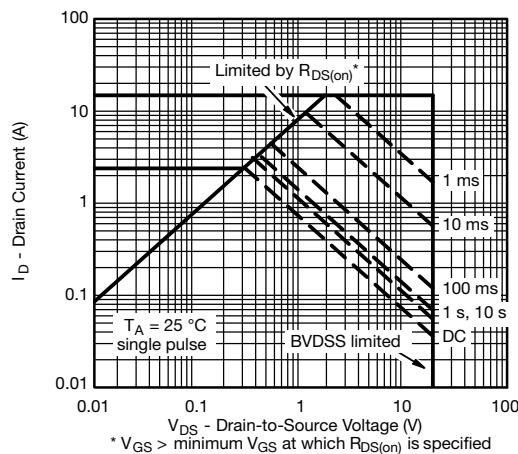
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



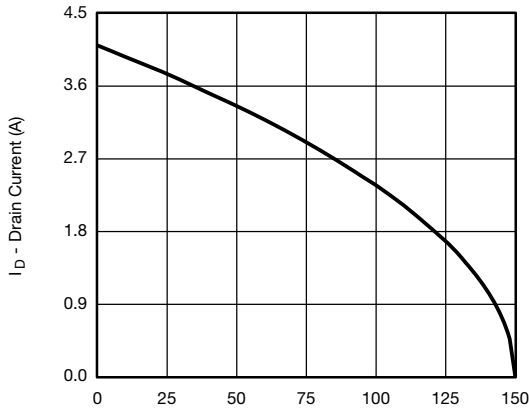
Single Pulse Power, Junction-to-Ambient



Safe Operating Area, Junction-to-Ambient

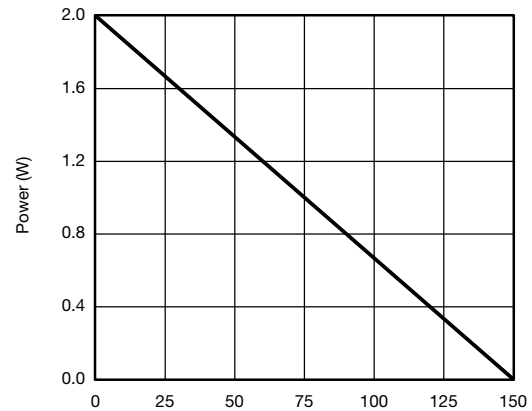


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



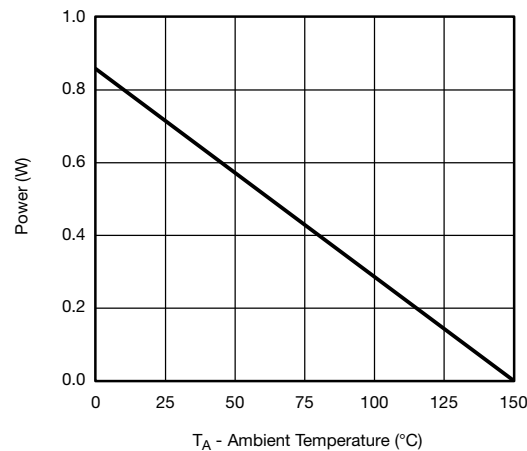
T_C - Case Temperature (°C)

Current Derating^a



T_C - Case Temperature (°C)

Power Derating, Junction-to-Foot



T_A - Ambient Temperature (°C)

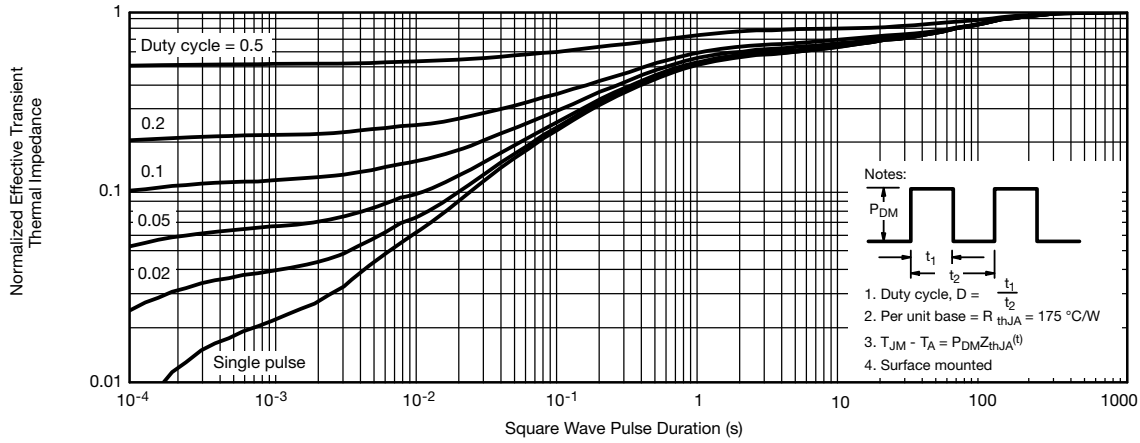
Power, Junction-to-Ambient

Note

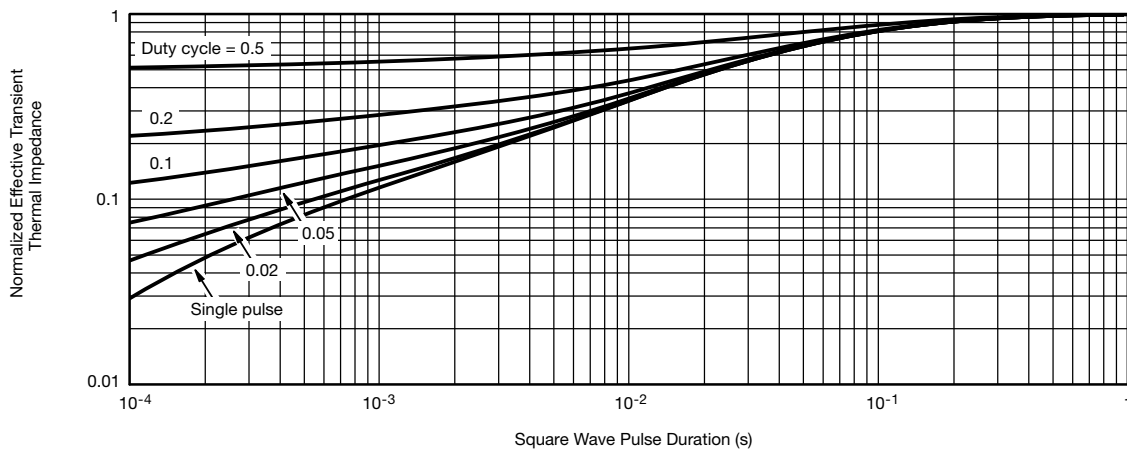
- a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

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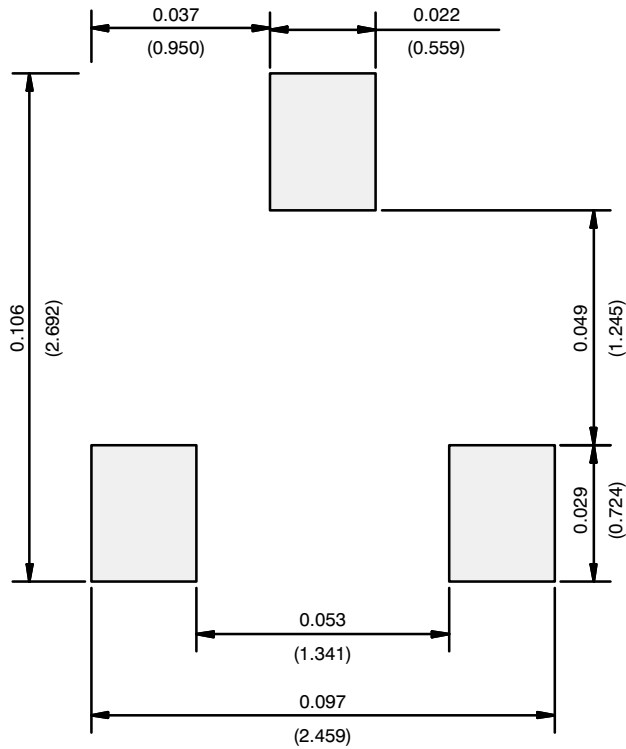
SOT-23 (TO-236): 3-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	0.89	1.12	0.035	0.044
A ₁	0.01	0.10	0.0004	0.004
A ₂	0.88	1.02	0.0346	0.040
b	0.35	0.50	0.014	0.020
c	0.085	0.18	0.003	0.007
D	2.80	3.04	0.110	0.120
E	2.10	2.64	0.083	0.104
E ₁	1.20	1.40	0.047	0.055
e	0.95 BSC		0.0374 Ref	
e ₁	1.90 BSC		0.0748 Ref	
L	0.40	0.60	0.016	0.024
L ₁	0.64 Ref		0.025 Ref	
S	0.50 Ref		0.020 Ref	
q	3°	8°	3°	8°

ECN: S-03946-Rev. K, 09-Jul-01
 DWG: 5479

RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads
Dimensions in Inches/(mm)

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